2SD1060



Bipolar Transistor 50V, 5A, Low VCE(sat) NPN TO-220-3L

http://onsemi.com

Applications

· Suitable for relay drivers, high-speed inverters, converters, and other general large-current switching

Features

• Low collector-to-emitter saturation voltage: VCE(sat)=0.3V max / IC=3A, IB= 0.3A

Specifications

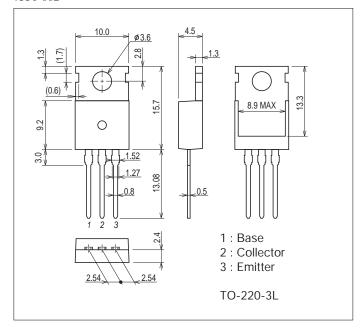
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		60	V
Collector-to-Emitter Voltage	VCEO		50	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		5	А
Collector Current (Pulse)	ICP		9	Α
Collector Dissipation	PC		1.75	W
		Tc=25°C	30	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7536-002



Product & Package Information

• Package : TO-220-3L

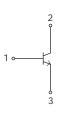
• JEITA, JEDEC : SC-46, TO-220AB

• Minimum Packing Quantity: 50 pcs./magazine

Marking



Electrical Connection



Semiconductor Components Industries, LLC, 2013

September, 2013 40412 TKIM TC-00002737/82207FA TIIM TC-00000844/913003TN(KT)/91098HA(KT)/D251MH/4017KI No.686-1/4

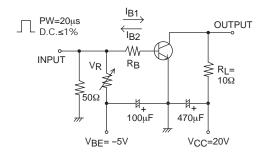
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0A			0.1	mA
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0A			0.1	mA
DC Current Gain	hFE1	V _{CE} =2V, I _C =1A	100*		280*	
	h _{FE} 2	V _{CE} =2V, I _C =2A	80			
Gain-Bandwidth Product	fŢ	V _{CE} =5V, I _C =1A		30		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		100		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	IC=3A, IB=0.3A			0.3	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=1mA, IE=0A	60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =1mA, I _C =0A	6			V
Turn-On Time	ton	See specified Test Circuit		0.1		μS
Storage Time	t _{stg}			1.4		μS
Fall Time	tf			0.2		μS

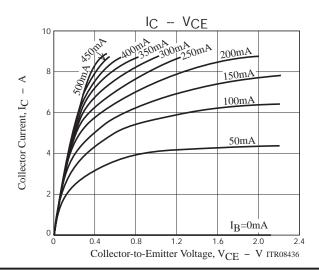
*: The 2SD1060 is classified by 1A hFE as follows

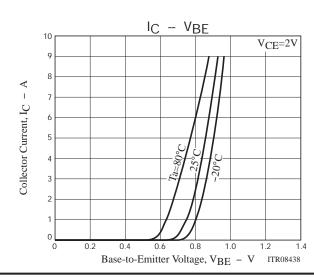
Rank	R	S
hFE	100 to 200	140 to 280

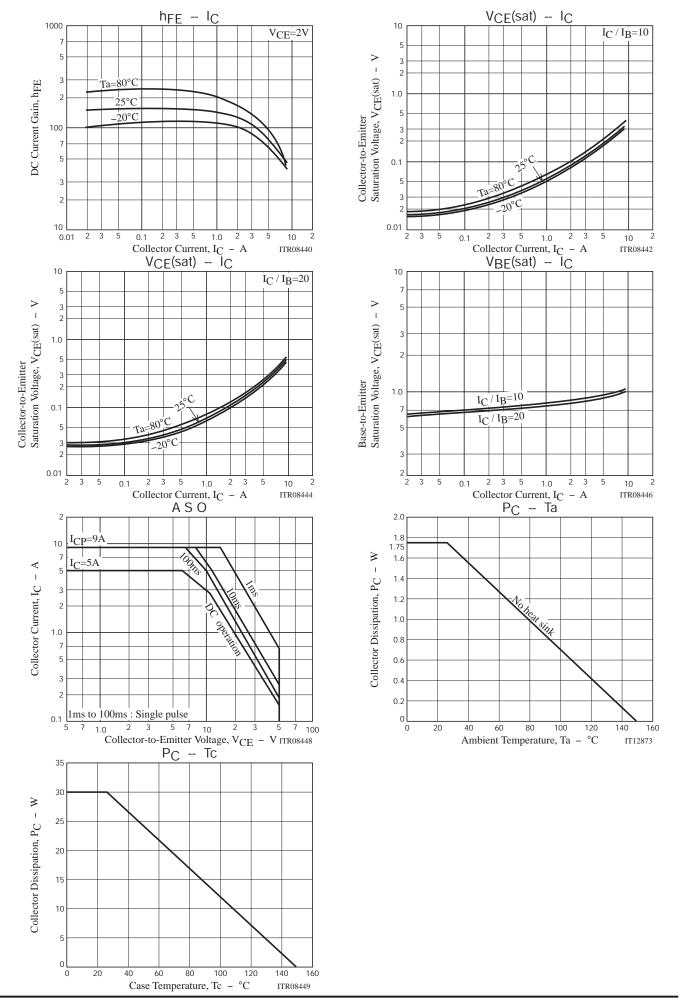
Switching Time Test Circuit



$$I_{C}=10I_{B1}=-10I_{B2}=2A$$







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